NSN 5962-01-415-6543

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:

1.5 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

High performance and programmable and low power

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.5 volts input and 7.0 volts input

Time Rating Per Chacteristic:

7.50 nanoseconds access

Memory Device Type:

Pal

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

20 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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